

UNITED STATES PATENT APPLICATION

FOR

METHOD AND APPARATUS FOR COOLING AN INTEGRATED CIRCUIT  
PACKAGE USING A COOLING FLUID

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# METHOD AND APPARATUS FOR COOLING AN INTEGRATED CIRCUIT PACKAGE USING A COOLING FLUID

## BACKGROUND OF THE INVENTION

### 5           1.     Field of the Invention

The described invention relates to the field of integrated circuit packages. In particular, the invention relates to an apparatus and method of cooling an integrated circuit package.

### 10           2.     Description of Related Art

15           An integrated circuit package houses an integrated circuit die. The integrated circuit die may generate a substantial amount of heat and may require substantial cooling to prevent the integrated circuit from overheating. In some cases, large heat sinks with fans are attached to the outside of the integrated circuit package.

20           Figure 1 is a schematic diagram that shows a prior art integrated circuit package 5. An integrated circuit die 10 is typically made from a semiconductor material such as silicon. The electrical components are formed on one side of the integrated circuit die, herein referred to as the “active surface” of the integrated circuit die.

25           The active surface 12 of the integrated circuit die 10 is electrically coupled to the package substrate 20 via solder bumps 30. In one embodiment, hundreds of solder bumps 30 may be used to provide electrical connectivity between the package substrate 20 and the integrated circuit die 10. In some cases the coefficient of expansion of the silicon integrated circuit die 10 may be many times lower than that

of the package substrate 20. An underfill material 40 is used to fill the areas around the solder bumps between the integrated circuit die 10 and the package substrate 20 and helps to reduce the stresses caused by the difference in thermal expansion of the two materials.

- 5           A heat spreader 50 covers the integrated circuit die and forms an air-filled chamber 52. In some cases, a thermal material 54 is placed between the integrated circuit die and the heat spreader to help conduct heat away from the integrated circuit die 10.

Various types of leads 60 extend from the integrated circuit package 5.

- 10       These leads are used to couple the integrated circuit package to a printed circuit board. The leads 60 may be any of various types such as solder bumps, ball grid array (BGA), pin grid array (PGA), surface mount, and so forth.

## BRIEF DESCRIPTION OF THE DRAWINGS

Figure 1 is a schematic diagram that shows a prior art integrated circuit package.

5        Figure 2 is a schematic diagram that shows one embodiment of an integrated circuit package having a cooling fluid.

Figure 3 is a schematic diagram that shows one embodiment of a top view of a microchannel surface.

10       Figure 4 shows an alternate embodiment of an integrated circuit package having a cooling fluid.

Figure 5 is a block diagram that shows an embodiment of using an external pump to help cool the integrated circuit package.

Figure 6 is a flowchart showing an embodiment of one method of forming an integrated circuit package having a cooling fluid.

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## DETAILED DESCRIPTION

A method and apparatus for cooling an integrated circuit die is described.

An integrated circuit package comprises a package substrate, an integrated circuit  
5 die having an active surface, and a cooling fluid. In one embodiment, an interposer  
is disposed between the package substrate and the integrated circuit die. The  
interposer establishes electrical connectivity between the integrated circuit die and  
the package substrate. In one embodiment, the cooling fluid is in contact with the  
active surface of the integrated circuit die. The integrated circuit die and/or the  
10 interposer may have a surface having microchannels ("a microchannel surface") that  
allows the cooling fluid to make better contact with the integrated circuit die and  
interposer, respectively.

Figure 2 is a schematic diagram that shows one embodiment of an integrated  
circuit package 105 having a cooling fluid 108. An integrated circuit die 110 is  
15 coupled to an interposer 114 that provides electrical connectivity between the  
integrated circuit die 110 and the package substrate 120. In one embodiment, the  
integrated circuit die 110 is coupled to the interposer 114 via solder bumps 130, and  
the interposer 114 is also coupled to the package substrate 120 via solder bumps  
132. An underfill material 140 fills the space between the interposer 114 and the  
20 package substrate 120. In one embodiment, both the integrated circuit die 110 and  
the interposer 114 comprise the same material. Therefore, the coefficients of  
thermal expansion of the integrated circuit die 110 and the interposer 114 are the  
same. This minimizes the creation of thermal stress, and therefore, no underfill  
material is needed to help couple the integrated circuit die 110 to the interposer 114.

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In one embodiment, the interposer 114 may provide electrical functionality in addition to electrical connectivity. For example, the interposer 114 may add capacitance to various nodes of the integrated circuit die 110. In one embodiment, the interposer 114 may comprise a second integrated circuit die that provides additional functionality. For example, the interposer 114 may serve as an optical to electrical interface for the first integrated circuit die 110. Thus, an optical signal may be input to the interposer 114, which provides a corresponding electrical signal to the first integrated circuit die 110.

A gap between the integrated circuit die 110 and the interposer 114 allows cooling fluid 108 to circulate between the two. Thus, the cooling fluid 108 makes contact with the active surface 112 of the integrated circuit die 110 and cools the integrated circuit die 110.

In one embodiment, the active surface of the integrated circuit die 110 is protected through a passivation layer (not shown), and the cooling fluid 108 is selected to be non-reactive with the passivation layer. In one example, the passivation layer may comprise polyimide.

The cooling fluid 108 may be any of various commercially available products. For example, the 3M Performance Materials Division of St. Paul, MN provides a family of fluorocarbon liquids (sold under the trademark brand name "Fluorinert") that range in boiling point from 56 degrees C to 253 degrees C. The cooling fluid 108 may be selected based on the one most suited to the particular temperatures expected to be produced within the integrated circuit package 105. It should be noted that although the term "cooling fluid" has been used herein, the

cooling fluid may exist in liquid and/or gas phases throughout different portions of the system.

In one embodiment, a cooling fluid 108 is selected that will change phase to yield an efficient thermal exchange. The phase change allows a higher rate of heat transfer at a low temperature drop. In one example, the cooling fluid 108 may evaporate as it moves across a hotter portion of the system, such as the active surface of the integrated circuit die, and may condense at a cooler portion of the system, such as at a heat spreader 150, that may additionally be coupled to a heat sink 154.

Cooling the active surface of the integrated circuit die, in particular, helps cool hot spots on the active surface and yields a more uniform surface temperature of the integrated circuit die. This allows more power to be dissipated by the integrated circuit die, even if the mean temperature of the active surface remains the same.

Heat spreader 150 covers the integrated circuit die 110 and the interposer 114 to form a chamber 152. In one embodiment, the cooling fluid 108 fills the entire chamber 152. A thermal material (not shown) may be placed between the integrated circuit die 110 and the heat spreader 150 to help conduct heat away from the integrated circuit die 110. Leads 160 allow attachment of the integrated circuit package to, for example, a printed circuit board. The leads 160 may be any of various types such as solder bumps, ball grid array (BGA), pin grid array (PGA), surface mount, and so forth.

In one embodiment, the integrated circuit die 110 and/or the interposer 114 may have a surface having microchannels 170 (“a microchannel surface”) that

allows the cooling fluid 108 to make better contact with the integrated circuit die 110 and interposer 114, respectively.

In one embodiment, the microchannels 170 are formed via any of various micromachining techniques such as etching or using a focused ion beam. However, 5 the microchannels 170 may alternatively be formed via other techniques such as, but not limited to, milling. In one embodiment, the microchannels 170 may have a depth of approximately half the depth of the integrated circuit die 110 and/or interposer 114.

In one embodiment, two or more vias 180 in the package substrate 120 may 10 be used to fill the chamber 152 with cooling fluid 108. One via may be used as an input as a second via allows air to escape the chamber 152. After the chamber 152 is filled, the vias 180 may be sealed, for example, by solder. In an alternate embodiment, two or more openings 182 through the heat spreader 150 may be used to fill the chamber 152. One opening may be used as an inlet, and the other opening 15 may be used to allow air to escape. The openings 182 are sealed after the chamber 152 is filled with cooling fluid 108. In one embodiment, the openings 182 may be pinched closed.

Figure 3 is a schematic diagram that shows one embodiment of a top view of a microchannel surface such as that of the integrated circuit die 110 or the interpose 20 114. In one embodiment, electrical connection to the microchannel surface may be achieved through solder bumps 130, such as those between the integrated circuit die 110 and the interpose 114. The solder bumps 130 may help form channels that funnel the cooling fluid substantially along the same path as the microchannels 170.



In one embodiment, a plurality of Micro-electromechanical system (MEMS) pumps are used to circulate cooling fluid 108 through the microchannels 170 of the integrated circuit die 110 and/or interposer 114.

MEMS is a technology that enables the miniaturization of electrical and mechanical structures. MEMS is a field created primarily in the silicon area, where the mechanical properties of silicon (or other materials such as aluminum, gold, etc.) are used to create miniature moving components. However, MEMS can also be applied to GaAs, quartz, glass and ceramic substrates. Using MEMS technology, various types of mechanical and non-mechanical pumps may be implemented.

Mechanical pumps include piezo-electric pumps and thermo pneumatic peristaltic pumps. These pumps typically use a membrane which, when pressure is exerted on the membrane, restricts or allows fluid flow as desired.

Non-mechanical pumps include electrokinetic pumps. Electrokinetic pumps use an ionic fluid and a current imposed at one end of the channel and collected at the other end of the channel. This current in the ionic fluid impels the ionic fluid towards the collection pad of the electrokinetic pump.

Another type of non-mechanical pump uses thermal bubbles to pump fluids through a microchannel. A heater heats the fluid until a bubble forms. The bubble exerts pressure to move the fluid. By arranging and controlling the heaters in a controlled manner, net movement of the cooling fluid may be achieved.

In one embodiment, a MEMS pump 190 is located in one or more microchannels to circulate the cooling fluid 108 through the microchannels 170.

Figure 4 shows an alternate embodiment of an integrated circuit package having a cooling fluid 208. An integrated circuit die 210 is coupled to a package

substrate 220 via solder bumps 232 and an underfill material 240. The surface of the integrated circuit die 210 has microchannels 270. In one embodiment, MEMS pumps 290 are located in or near the microchannels 270 and help circulate cooling fluid 208 through the microchannels 270. In one embodiment, a thermal material 285 helps couple the integrated circuit die 210 to a heat spreader 250. In one embodiment, openings 282 or vias (not shown) may be used to fill the internal chamber 252 with the cooling fluid 208.

Figure 5 is a block diagram that shows an embodiment of using an external pump 290 to help cool an integrated circuit package 105,205. In one embodiment, the external pump 290 is coupled to openings 182,282 of the integrated circuit package. The external pump 290 circulates the cooling fluid 108, 208 within the integrated circuit package. In one embodiment, the external pump 290 circulates the cooling fluid to a heat exchanger 292 remote from the integrated circuit package, which may substantially improve the cooling efficiency of the system.

Figure 6 is a flowchart showing an embodiment of one method of forming an integrated circuit package 105 having a cooling fluid 108. The flowchart begins at block 300, and continues at block 302, at which the interposer 114 is attached to the package substrate 120. In one embodiment, the interposer 114 is attached to the package substrate 120 via solder bumps. In one embodiment, the interposer 114 is positioned and then heated until the solder bumps melt to form an electrical connection with the package substrate 120. At block 304, an underfill material is applied to the interposer and allowed to fill the space between the interposer 114 and the package substrate 120.

The flowchart continues at block 306, at which the integrated circuit die 110 is attached to the interposer 114. In one embodiment, the integrated circuit die 110 is attached to the interposer 114 via solder bumps by heating the integrated circuit die 110 until the solder bumps melt to form the electrical connection. At block 308,  
5 the substrate 120, the integrated circuit die 110 and the interposer 114 are covered with a heat spreader 150, and create an internal chamber 152. The internal chamber 152 is filled with cooling fluid 108 at block 310. In one embodiment, this may be achieved by filling the chamber 152 using openings through the package substrate 120, such as through vias 180 (see Figure 2). In an alternative embodiment, this  
10 may be achieved through openings 182 (see Figure 2) in the heat spreader 150.

Thus, a method and apparatus for cooling an integrated circuit die is disclosed. However, the specific embodiments and methods described herein are merely illustrative. Numerous modifications in form and detail may be made without departing from the scope of the invention as claimed below. The invention  
15 is limited only by the scope of the appended claims.